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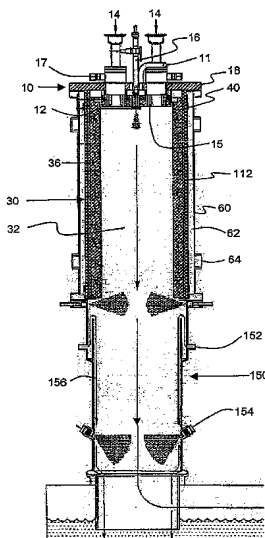
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(54) Title: REACTOR DESIGN TO REDUCE PARTICLE DEPOSITION DURING PROCESS ABATEMENT



(57) Abstract: Systems and methods are provided for controlled combustion and decomposition of gaseous pollutants while reducing deposition of unwanted reaction products from within the treatment systems. Exemplary systems include a novel thermal reaction chamber design having stacked porous ceramic rings through which fluid, e.g., gases, may be directed to form a boundary layer along the interior wall of the thermal reaction chamber, thereby reducing particulate matter buildup thereon. The systems may further include the introduction of fluids from the center pilot jet to alter the aerodynamics of the interior of the thermal reaction chamber.

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REACTOR DESIGN TO REDUCE PARTICLE
DEPOSITION DURING PROCESS ABATEMENT

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The present application claims priority from U.S. Patent Application Serial No. 10/987,921, filed November 12, 2004, which is hereby incorporated by reference herein in its entirety.

10 FIELD OF THE INVENTION

The present invention relates to improved systems and methods for the abatement of industrial effluent fluids, such as effluent gases produced in semiconductor manufacturing processes, while reducing the deposition of reaction products in the treatment systems.

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BACKGROUND OF THE INVENTION

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The gaseous effluents from the manufacturing of semiconductor materials, devices, products and memory articles involve a wide variety of chemical compounds used and produced in the process facility. These compounds include inorganic and organic compounds, breakdown products of photo-resist and other reagents, and a wide variety of other gases that must be removed from the waste gas before being vented from the process facility into the atmosphere.

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Semiconductor manufacturing processes utilize a variety of chemicals, many of which have extremely low human tolerance levels. Such materials include gaseous hydrides of antimony, arsenic, boron, germanium, nitrogen, phosphorous, silicon, selenium, silane, silane mixtures with phosphine, argon, hydrogen, organosilanes, halosilanes, halogens, organometallics and other organic compounds.

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Halogens, e.g., fluorine (F₂) and other fluorinated compounds, are particularly problematic among the various components requiring abatement. The electronics industry uses perfluorinated compounds (PFCs) in wafer processing tools to remove residue from deposition steps and to etch thin films. PFCs are recognized to be strong contributors to global warming and the electronics industry is working to reduce the emissions of these gases. The most commonly used PFCs include, but are not limited to, CF₄, C₂F₆, SF₆,

C₃F₈, C₄H₈, C₄H₈O and NF₃. In practice, these PFCs are dissociated in a plasma to generate highly reactive fluoride ions and fluorine radicals, which do the actual cleaning and/or etching. The effluent from these processing operations include mostly fluorine, silicon tetrafluoride (SiF₄), hydrogen fluoride (HF), carbonyl fluoride (COF₂), CF₄ and C₂F₆.

A significant problem of the semiconductor industry has been the removal of these materials from the effluent gas streams. While virtually all U.S. semiconductor manufacturing facilities utilize scrubbers or similar means for treatment of their effluent gases, the technology employed in these facilities is not capable of removing all toxic or otherwise unacceptable impurities.

One solution to this problem is to incinerate the process gas to oxidize the toxic materials, converting them to less toxic forms. Such systems are almost always over-designed in terms of treatment capacity, and typically do not have the ability to safely deal with a large number of mixed chemistry streams without posing complex reactive chemical risks. Further, conventional incinerators typically achieve less than complete combustion thereby allowing the release of pollutants, such as carbon monoxide (CO) and hydrocarbons (HC), to the atmosphere. Furthermore, one of the problems of great concern in effluent treatment is the formation of acid mist, acid vapors, acid gases and NO_x (NO, NO₂) prior to discharge. A further limitation of conventional incinerators is their inability to mix sufficient combustible fuel with a nonflammable process stream in order to render the resultant mixture flammable and completely combustible.

Oxygen or oxygen-enriched air may be added directly into the combustion chamber for mixing with the waste gas to increase combustion temperatures, however, oxides, particularly silicon oxides may be formed and these oxides tend to deposit on the walls of the combustion chamber. The mass of silicon oxides formed can be relatively large and the gradual deposition within the combustion chamber can induce poor combustion or cause clogging of the combustion chamber, thereby necessitating increased maintenance of the equipment. Depending on the circumstances, the cleaning operation of the abatement apparatus may need to be performed once or twice a week.

It is well known in the arts that the destruction of a halogen gas requires high temperature conditions. To handle the high temperatures, some prior art combustion chambers have included a circumferentially continuous combustion chamber made of ceramic materials to oxidize the effluent within the chamber (see, e.g., U.S. Patent No.

6,494,711 in the name of Takemura et al., issued December 17, 2002). However, under the extreme temperatures needed to abate halogen gases, these circumferentially continuous ceramic combustion chambers crack due to thermal shock and thus, the thermal insulating function of the combustion chamber fails. An alternative includes the controlled decomposition/oxidation (CDO) systems of the prior art, wherein the effluent gases undergo combustion in the metal inlet tubes, however, the metal inlet tubes of the CDO's are physically and corrosively compromised at the high temperatures, e.g., $\approx 1260^{\circ}\text{C}$ - 1600°C , needed to efficiently decompose halogen compounds such as CF_4 .

Accordingly, it would be advantageous to provide an improved thermal reactor for the decomposition of highly thermally resistant contaminants in a waste gas that provides high temperatures, through the introduction of highly flammable gases, to ensure substantially complete decomposition of said waste stream while simultaneously reducing deposition of unwanted reaction products within the thermal reaction unit. Further, it would be advantageous to provide an improved thermal reaction chamber that does not succumb to the extreme temperatures and corrosive conditions needed to effectively abate the waste gas.

SUMMARY OF INVENTION

The present invention relates to methods and systems for providing controlled decomposition of gaseous liquid crystal display (LCD) and semiconductor wastes in a thermal reactor while reducing accumulation of the particulate products of said decomposition within the system. The present invention further relates to an improved thermal reactor design to reduce reactor chamber cracking during the decomposition of the gaseous waste gases.

In one aspect, the present invention relates to a thermal reactor for removing pollutant from waste gas, the thermal reactor comprising:

a) a thermal reaction unit comprising:

- i) an exterior wall having a generally tubular form and a plurality of perforations for passage of a fluid therethrough, wherein the exterior wall includes at least two sections along its length, and wherein adjacent sections are interconnected by a coupling;
- ii) a reticulated ceramic interior wall defining a thermal reaction chamber, wherein the interior wall has a generally tubular form and concentric with

the exterior wall, wherein the interior wall comprises at least two ring sections in a stacked arrangement;

iii) at least one waste gas inlet in fluid communication with the thermal reaction chamber for introducing a waste gas therein; and

5 iv) at least one fuel inlet in fluid communication with the thermal reaction chamber for introducing a fuel that upon combustion produces temperature that decomposes said waste gas in the thermal reaction chamber; and

10 v) means for directing a fluid through the perforations of the exterior wall and the reticulated ceramic interior wall to reduce the deposition and accumulation of particulate matter thereon; and

b) a water quench.

In yet another aspect, the present invention relates to a thermal reactor for removing pollutant from waste gas, the thermal reactor comprising:

a) a thermal reaction unit comprising:

15 i) an exterior wall having a generally tubular form;

ii) an interior wall having a generally tubular form and concentric with the exterior wall, wherein the interior wall defines a thermal reaction chamber;

20 iii) a reticulated ceramic plate positioned at or within the interior wall of the thermal reaction unit, wherein the reticulated ceramic plate seals one end of the thermal reaction chamber;

iii) at least one waste gas inlet in fluid communication with the thermal reaction chamber for introducing a waste gas therein; and

25 iv) at least one fuel inlet in fluid communication with the thermal reaction chamber for introducing a fuel that upon combustion produces temperature that decomposes said waste gas within the thermal reaction unit; and

b) a water quench.

In a further aspect, the present invention relates to a method for controlled decomposition of gaseous pollutant in a waste gas in a thermal reactor, the method comprising:

30 i) introducing the waste gas to a thermal reaction chamber through at least one waste gas inlet, wherein the thermal reaction chamber is defined by reticulated ceramic walls;

ii) introducing at least one combustible fuel to the thermal reaction chamber;

iii) igniting the combustible fuel in the thermal reaction chamber to effect formation of reaction products and heat evolution, wherein the heat evolved decomposes the waste gas;

iv) injecting additional fluid through the reticulated ceramic walls into the thermal reaction chamber contemporaneously with the combusting of the combustible fuel, wherein the additional fluid is injected in a continuous mode at a force exceeding that of the reaction products approaching the reticulated ceramic walls of the thermal reaction chamber thereby inhibiting deposition of the reaction products thereon; and

v) flowing the stream of reaction products into a water quench to capture the reaction products therein.

Other aspects and advantages of the invention will be more fully apparent from the ensuing disclosure and appended claims

BRIEF DESCRIPTION OF THE DRAWINGS

Figure 1 is a cut away view of the thermal reaction unit, the inlet adaptor and the lower quenching chamber according to the invention

Figure 2 is an elevational view of the interior plate of the inlet adaptor according to the invention.

Figure 3 is a partial cut-away view of the inlet adaptor according to the invention.

Figure 4 is a view of a center jet according to the invention for introducing a high velocity air stream into the thermal reaction chamber.

Figure 5 is a cut away view of the inlet adaptor and the thermal reaction unit according to the invention.

Figure 6A is an elevational view of a ceramic ring of the thermal reaction unit according to the invention.

Figure 6B is a partial cut-away view of the ceramic ring.

Figure 6C is a partial cut-away view of ceramic rings stacked upon one another to define the thermal reaction chamber of the present invention.

Figure 7 is a view of the sections of the perforated metal shell according to the invention.

Figure 8 is an exterior view of the thermal reaction unit according to the invention.

Figure 9 is a partial cut-away view of the inlet adaptor/thermal reaction unit joint according to the invention.

Figure 10A illustrates deposition of residue on the interior plate of the inlet adaptor of the prior art.

5 Figure 10B illustrates deposition of residue on the interior plate of the inlet adaptor according to the invention.

Figure 11A illustrates deposition of residue on the interior walls of the thermal reaction unit of the prior art.

10 Figure 11B illustrates deposition of residue on the interior walls of the thermal reaction unit according to the invention.

Figure 12 is a partial cut-away view of the shield positioned between the thermal reaction unit and the lower quenching chamber according to the invention.

DETAILED DESCRIPTION

15 The present invention relates to methods and systems for providing controlled decomposition of effluent gases in a thermal reactor while reducing accumulation of deposition products within the system. The present invention further relates to an improved thermal reactor design to reduce thermal reaction unit cracking during the high temperature decomposition of effluent gases.

20 Waste gas to be abated may include species generated by a semiconductor process and/or species that were delivered to and egressed from the semiconductor process without chemical alteration. As used herein, the term "semiconductor process" is intended to be broadly construed to include any and all processing and unit operations in the manufacture of semiconductor products and/or LCD products, as well as all operations involving
25 treatment or processing of materials used in or produced by a semiconductor and/or LCD manufacturing facility, as well as all operations carried out in connection with the semiconductor and/or LCD manufacturing facility not involving active manufacturing (examples include conditioning of process equipment, purging of chemical delivery lines in preparation of operation, etch cleaning of process tool chambers, abatement of toxic or
30 hazardous gases from effluents produced by the semiconductor and/or LCD manufacturing facility, etc.).

The improved thermal reaction system disclosed herein has a thermal reaction unit 30 and a lower quenching chamber 150 as shown in Fig. 1. The thermal reaction unit 30

includes a thermal reaction chamber 32, and an inlet adaptor 10 including a top plate 18, at least one waste gas inlet 14, at least one fuel inlet 17, optionally at least one oxidant inlet 11, burner jets 15, a center jet 16 and an interior plate 12 which is positioned at or within the thermal reaction chamber 32 (see also Fig. 3 for a schematic of the inlet adaptor independent of the thermal reaction unit). The inlet adaptor includes the fuel and oxidant gas inlets to provide a fuel rich gas mixture to the system for the destruction of contaminants. When oxidant is used, the fuel and oxidant may be pre-mixed prior to introduction into the thermal reaction chamber. Fuels contemplated herein include, but are not limited to, hydrogen, methane, natural gas, propane, LPG and city gas, preferably natural gas. Oxidants contemplated herein include, but are limited to, oxygen, ozone, air, clean dry air (CDA) and oxygen-enriched air. Waste gases to be abated comprise a species selected from the group consisting of CF_4 , C_2F_6 , SF_6 , C_3F_8 , C_4H_8 , $\text{C}_4\text{H}_8\text{O}$, SiF_4 , BF_3 , NF_3 , BH_3 , B_2H_6 , B_5H_9 , NH_3 , PH_3 , SiH_4 , SeH_2 , F_2 , Cl_2 , HCl , HF , HBr , WF_6 , H_2 , $\text{Al}(\text{CH}_3)_3$, primary and secondary amines, organosilanes, organometallics, and halosilanes.

In one embodiment of the invention, the interior walls of the waste gas inlet 14 may be altered to reduce the affinity of particles for the interior walls of the inlet. For example, a surface may be electropolished to reduce the mechanical roughness (Ra) to a value less than 30, more preferably less than 17, most preferably less than 4. Reducing the mechanical roughness reduces the amount of particulate matter that adheres to the surface as well as improving the corrosion resistance of the surface. In the alternative, the interior wall of the inlet may be coated with a fluoropolymer coating, for example Teflon® or Halar®, which will also act to reduce the amount of particulate matter adhered at the interior wall as well as allow for easy cleaning. Pure Teflon® or pure Halar® layers are preferred, however, these materials are easily scratched or abraded. As such, in practice, the fluoropolymer coating is applied as follows. First the surface to be coated is cleaned with a solvent to remove oils, etc. Then, the surface is bead-blasted to provide texture thereto. Following texturization, a pure layer of fluoropolymer, e.g., Teflon®, a layer of ceramic filled fluoropolymer, and another pure layer of fluoropolymer are deposited on the surface in that order. The resultant fluoropolymer-containing layer is essentially scratch-resistant.

In another embodiment of the invention, the waste gas inlet 14 tube is subjected to thermophoresis, wherein the interior wall of the inlet is heated thereby reducing particle adhesion thereto. Thermophoresis may be effected by actually heating the surface of the

interior wall with an on-line heater or alternatively, a hot nitrogen gas injection may be used, whereby 50-100 L per minute of hot nitrogen gas flows through the inlet. The additional advantage of the latter is the nitrogen gas flow minimizes the amount of time waste gases reside in the inlet thereby minimizing the possibility of nucleation therein.

5 Prior art inlet adaptors have included limited porosity ceramic plates as the interior plate of the inlet adaptor. A disadvantage of these limited porosity interior plates includes the accumulation of particles on said surface, eventually leading to inlet port clogging and flame detection error. The present invention overcomes these disadvantages by using a reticulated ceramic foam as the interior plate 12. Fig. 2 represents an elevational view of
10 the interior plate 12, including the inlet ports 14, burner jets 15, a center jet port 16 (to be discussed hereinafter) and the reticulated ceramic foam 20 of the interior plate. Importantly, the reticulated ceramic foam 20 has a plurality of pores disposed therethrough. As such, the invention contemplates the passage of fluids through the pores of the interior plate to the thermal reaction chamber 32 to reduce the deposition of
15 particulate matter at the surface of the interior plate 12 and the walls of the thermal reaction unit 30 proximate to the interior plate 12. The fluid may include any gas that is preferably pressurized to a suitable pressure, which upon diffusion through the material is sufficient to reduce deposition on the interior plate while not detrimentally affecting the abatement treatment in the thermal reaction chamber. Gases contemplated herein for
20 passage through the pores of the interior plate 12 include air, CDA, oxygen-enriched air, oxygen, ozone and inert gases, e.g., Ar, N₂, etc., and should be devoid of fuels. Further, the fluid may be introduced in a continuous or a pulsating mode, preferably a continuous mode.

Although not wishing to be bound by theory, the reticulated ceramic foam interior
25 plate helps prevent particle buildup on the interior plate in part because the exposed planar surface area is reduced thereby reducing the amount of surface available for build-up, because the reticulation of the interior plate provides smaller attachment points for growing particulate matter which will depart the interior plate upon attainment of a critical mass and because the air passing through the pores of the interior plate forms a "boundary
30 layer," keeping particles from migrating to the surface for deposition thereon.

Ceramic foam bodies have an open cell structure characterized by a plurality of interconnected voids surrounded by a web of ceramic structure. They exhibit excellent physical properties such as high strength, low thermal mass, high thermal shock resistance,

and high resistance to corrosion at elevated temperatures. Preferably, the voids are uniformly distributed throughout the material and the voids are of a size that permits fluids to easily diffuse through the material. The ceramic foam bodies should not react appreciably with PFC's in the effluent to form highly volatile halogen species. The ceramic foam bodies may include alumina materials, magnesium oxide, refractory metal oxides such as ZrO_2 , silicon carbide and silicon nitride, preferably higher purity alumina materials, e.g., spinel, and yttria-doped alumina materials. Most preferably, the ceramic foam bodies are ceramic bodies formed from yttria-doped alumina materials and yttria-stabilized zirconia-alumina (YZA). The preparation of ceramic foam bodies is well within the knowledge of those skilled in the art.

To further reduce particle build-up on the interior plate 12, a fluid inlet passageway may be incorporated into the center jet 16 of the inlet adaptor 10 (see for example Figs. 1, 3 and 5 for placement of the center jet in the inlet adaptor). An embodiment of the center jet 16 is illustrated in Fig. 4, said center jet including a pilot injection manifold tube 24, pilot ports 26, a pilot flame protective plate 22 and a fastening means 28, e.g., threading complementary to threading on the inlet adaptor, whereby the center jet and the inlet adaptor may be complementarily mated with one another in a leak-tight fashion. The pilot flame of the center jet 16 is used to ignite the burner jets 15 of the inlet adaptor. Through the center of the center jet 16 is a bore-hole 25 through which a stream of high velocity fluid may be introduced to inject into the thermal reaction chamber 32 (see, e.g., Fig. 5). Although not wishing to be bound by theory, it is thought that the high velocity air alters the aerodynamics and pulls gaseous and/or particulate components of the thermal reaction chamber towards the center of the chamber thereby keeping the particulate matter from getting close to the top plate and the chamber walls proximate to the top plate. The high velocity fluid may include any gas sufficient to reduce deposition on the interior walls of the thermal reaction unit while not detrimentally affecting the abatement treatment in the thermal reaction chamber. Further, the fluid may be introduced in a continuous or a pulsating mode, preferably a continuous mode. Gases contemplated herein include air, CDA, oxygen-enriched air, oxygen, ozone and inert gases, e.g., Ar, N_2 , etc. Preferably, the gas is CDA and may be oxygen-enriched. In another embodiment, the high velocity fluid is heated prior to introduction into the thermal reaction chamber.

In yet another embodiment, the thermal reaction unit includes a porous ceramic cylinder design defining the thermal reaction chamber 32. High velocity air may be

directed through the pores of the thermal reaction unit 30 to at least partially reduce particle buildup on the interior walls of the thermal reaction unit. The ceramic cylinder of the present invention includes at least two ceramic rings stacked upon one another, for example as illustrated in Fig. 6C. More preferably, the ceramic cylinder includes at least
5 about two to about twenty rings stacked upon one another. It is understood that the term "ring" is not limited to circular rings *per se*, but may also include rings of any polygonal or elliptical shape. Preferably, the rings are generally tubular in form.

Figure 6C is a partial cut-away view of the ceramic cylinder design of the present invention showing the stacking of the individual ceramic rings 36 having a complimentary
10 ship-lap joint design, wherein the stacked ceramic rings define the thermal reaction chamber 32. The uppermost ceramic ring 40 is designed to accommodate the inlet adaptor. It is noted that the joint design is not limited to lap joints but may also include beveled joints, butt joints, lap joints and tongue and groove joints. Gasketing or sealing means, e.g., GRAFOIL® or other high temperature materials, positioned between the
15 stacked rings is contemplated herein, especially if the stacked ceramic rings are butt jointed. Preferably, the joints between the stacked ceramic rings overlap, e.g., ship-lap, to prevent infrared radiation from escaping from the thermal reaction chamber.

Each ceramic ring may be a circumferentially continuous ceramic ring or alternatively, may be at least two sections that may be joined together to make up the
20 ceramic ring. Figure 6A illustrates the latter embodiment, wherein the ceramic ring 36 includes a first arcuate section 38 and a second arcuate section 40, and when the first and second arcuate sections are coupled together, a ring is formed that defines a portion of the thermal reaction chamber 32. The ceramic rings are preferably formed of the same materials as the ceramic foam bodies discussed previously, e.g., YZA.

25 The advantage of having a thermal reaction chamber defined by individual stacked ceramic rings includes the reduction of cracking of the ceramic rings of the chamber due to thermal shock and concomitantly a reduction of equipment costs. For example, if one ceramic ring cracks, the damaged ring may be readily replaced for a fraction of the cost and the thermal reactor placed back online immediately.

30 The ceramic rings of the invention must be held to another to form the thermal reaction unit 30 whereby high velocity air may be directed through the pores of the ceramic rings of the thermal reaction unit to at least partially reduce particle buildup at the interior walls of the thermal reaction unit. Towards that end, a perforated metal shell may

be used to encase the stacked ceramic rings of the thermal reaction unit as well as control the flow of axially directed air through the porous interior walls of the thermal reaction unit. Figure 7 illustrates an embodiment of the perforated metal shell 110 of the present invention, wherein the metal shell has the same general form of the stacked ceramic rings, e.g., a circular cylinder or a polygonal cylinder, and the metal shell includes at least two attachable sections 112 that may be joined together to make up the general form of the ceramic cylinder. The two attachable sections 112 include ribs 114, e.g., clampable extensions 114, which upon coupling put pressure on the ceramic rings thereby holding the rings to one another.

The metal shell 110 has a perforated pattern whereby preferably more air is directed towards the top of the thermal reaction unit, e.g., the portion closer to the inlet adaptor 10, than the bottom of the thermal reaction unit, e.g., the lower chamber (see Figs. 7 and 8). In the alternative, the perforated pattern is the same throughout the metal shell. As defined herein, "perforations" may represent any array of openings through the metal shell that do not compromise the integrity and strength of the metal shell, while ensuring that the flow of axially directed air through the porous interior walls may be controlled. For example, the perforations may be holes having circular, polygonal or elliptical shapes or in the alternative, the perforations may be slits of various lengths and widths. In one embodiment, the perforations are holes 1/16" in diameter, and the perforation pattern towards the top of the thermal reaction unit has 1 hole per square inch, while the perforation pattern towards the bottom of the thermal reaction unit has 0.5 holes per square inch (in other words 2 holes per 4 square inches). Preferably, the perforation area is about 0.1 % to 1 % of the area of the metal shell. The metal shell is constructed from corrosion-resistant metals including, but not limited to: stainless steel; austenitic nickel-chromium-iron alloys such as Inconel® 600, 601, 617, 625, 625 LCF, 706, 718, 718 SPF, X-750, MA754, 783, 792, and HX; and other nickel-based alloys such as Hastelloy B, B2, C, C22, C276, C2000, G, G2, G3 and G30.

Referring to Figure 8, the thermal reaction unit of the invention is illustrated. The ceramic rings 36 are stacked upon one another, at least one layer of a fibrous blanket is wrapped around the exterior of the stacked ceramic rings and then the sections 112 of the metal shell 110 are positioned around the fibrous blanket and tightly attached together by coupling the ribs 114. The fibrous blanket can be any fibrous inorganic material having a low thermal conductivity, high temperature capability and an ability to deal with the

thermal expansion coefficient mismatch of the metal shell and the ceramic rings. Fibrous blanket material contemplated herein includes, but is not limited to, spinel fibers, glass wool and other materials comprising aluminum silicates. In the alternative, the fibrous blanket may be a soft ceramic sleeve.

5 In practice, fluid flow is axially and controllably introduced through the perforations of the metal shell, the fibrous blanket and the reticulated ceramic rings of the cylinder. The fluid experiences a pressure drop from the exterior of the thermal reaction unit to the interior of the thermal reaction unit in a range from about 0.05 psi to about 0.30 psi, preferably about 0.1 psi to 0.2 psi. The fluid may be introduced in a continuous or a
10 pulsating mode, preferably a continuous mode to reduce the recirculation of the fluid within the thermal reaction chamber. It should be appreciated that an increased residence time within the thermal reaction chamber, wherein the gases are recirculated, results in the formation of larger particulate material and an increased probability of deposition within the reactor. The fluid may include any gas sufficient to reduce deposition on the interior
15 walls of the ceramic rings while not detrimentally affecting the abatement treatment in the thermal reaction chamber. Gases contemplated include air, CDA, oxygen-enriched air, oxygen, ozone and inert gases, e.g., Ar, N₂, etc.

To introduce fluid to the walls of the thermal reaction unit for passage through to the thermal reaction chamber 32, the entire thermal reaction unit 30 is encased within an
20 outer stainless steel reactor shell 60 (see, e.g., Fig. 1), whereby an annular space 62 is created between the interior wall of the outer reactor shell 60 and the exterior wall of the thermal reaction unit 30. Fluids to be introduced through the walls of the thermal reaction unit may be introduced at ports 64 positioned on the outer reactor shell 60.

Referring to Fig. 1, the interior plate 12 of the inlet adaptor 10 is positioned at or
25 within the thermal reaction chamber 32 of the thermal reaction unit 30. To ensure that gases within the thermal reaction unit do not leak from the region where the inlet adaptor contacts the thermal reaction unit, a gasket or seal 42 is preferably positioned between the top ceramic ring 40 and the top plate 18 (see, e.g., Fig. 9). The gasket or seal 42 may be GRAFOIL® or some other high temperature material that will prevent leakage of blow-off
30 air through the top plate/thermal reaction unit joint, i.e., to maintain a backpressure behind the ceramic rings for gas distribution.

Figs. 10A and 10B show the buildup of particulate matter on a prior art interior plate and an interior plate according to the present invention, respectively. It can be seen

that the buildup on the interior plate of the present invention (having a reticulated foam plate with fluid emanating from the pores, a reticulated ceramic cylinder with fluid emanating from the pores and high velocity fluid egression from the center jet) is substantially reduced relative to the interior plate of the prior art, which is devoid of the novel improvements disclosed herein.

Figs. 11A and 11B illustrate prior art thermal reaction units and the thermal reaction unit according to the present invention, respectively. It can be seen that the buildup of particulate matter on the interior walls of the thermal reaction unit of the present invention is substantially reduced relative to prior art thermal reaction unit walls. Using the apparatus and method described herein, the amount of particulate buildup at the interior walls of the thermal reaction unit is reduced by at least 50%, preferably at least 70% and more preferably at least 80%, relative to prior art units oxidizing an equivalent amount of effluent gas.

Downstream of the thermal reaction chamber is a water quenching means positioned in the lower quenching chamber 150 to capture the particulate matter that egresses from the thermal reaction chamber. The water quenching means may include a water curtain as disclosed in co-pending U.S. Patent Application No. 10/249,703 in the name of Glenn Tom et al., entitled "Gas Processing System Comprising a Water Curtain for Preventing Solids Deposition on Interior Walls Thereof," which is hereby incorporated by reference in the entirety. Referring to Fig. 1, the water for the water curtain is introduced at inlet 152 and water curtain 156 is formed, whereby the water curtain absorbs the heat of the combustion and decomposition reactions occurring in the thermal reaction unit 30, eliminates build-up of particulate matter on the walls of the lower quenching chamber 150, and absorbs water soluble gaseous products of the decomposition and combustion reactions, e.g., CO₂, HF, etc.

To ensure that the bottom-most ceramic ring does not get wet, a shield 202 (see, e.g., Fig. 12) may be positioned between the bottom-most ceramic ring 198 and the water curtain in the lower chamber 150. Preferably, the shield is L-shaped and assumes the three-dimensional form of the bottom-most ceramic ring, e.g., a circular ring, so that water does not come in contact with the bottom-most ceramic ring. The shield may be constructed from any material that is water- and corrosion-resistant and thermally stable including, but not limited to: stainless steel; austenitic nickel-chromium- iron alloys such as Inconel® 600, 601, 617, 625, 625 LCF, 706, 718, 718 SPF, X-750, MA754, 783, 792,

and HX; and other nickel-based alloys such as Hastelloy B, B2, C, C22, C276, C2000, G, G2, G3 and G30.

In practice, effluent gases enter the thermal reaction chamber 32 from at least one inlet provided in the inlet adaptor 10, and the fuel/oxidant mixture enter the thermal reaction chamber 32 from at least one burner jet 15. The pilot flame of the center jet 16 is used to ignite the burner jets 15 of the inlet adaptor, creating thermal reaction unit temperatures in a range from about 500°C to about 2000°C. The high temperatures facilitate decomposition of the effluent gases that are present within the thermal reaction chamber. It is also possible that some effluent gases undergo combustion/oxidation in the presence of the fuel/oxidant mixture. The pressure within the thermal reaction chamber is in a range from about 0.5 atm to about 5 atm, preferably slightly subatmospheric, e.g., about 0.98 atm to about 0.99 atm.

Following decomposition/combustion, the effluent gases pass to the lower chamber 150 wherein a water curtain 156 may be used to cool the walls of the lower chamber and inhibit deposition of particulate matter on the walls. It is contemplated that some particulate matter and water soluble gases may be removed from the gas stream using the water curtain 156. Further downstream of the water curtain, a water spraying means 154 may be positioned within the lower quenching chamber 150 to cool the gas stream, and remove the particulate matter and water soluble gases. Cooling the gas stream allows for the use of lower temperature materials downstream of the water spraying means thereby reducing material costs. Gases passing through the lower quenching chamber may be released to the atmosphere or alternatively may be directed to additional treatment units including, but not limited to, liquid/liquid scrubbing, physical and/or chemical adsorption, coal traps, electrostatic precipitators, and cyclones. Following passage through the thermal reaction unit and the lower quenching chamber, the concentration of the effluent gases is preferably below detection limits, e.g., less than 1 ppm. Specifically, the apparatus and method described herein removes greater than 90% of the toxic effluent components that enter the abatement apparatus, preferably greater than 98%, most preferably greater than 99.9%.

In an alternative embodiment, an "air knife" is positioned within the thermal reaction unit. Referring to Fig. 12, fluid may be intermittently injected into the air knife inlet 206, which is situated between the bottom-most ceramic ring 198 and the water quenching means in the lower quenching chamber 150. The air knife inlet 206 may be

incorporated into the shield 202 which prevents water from wetting the bottom-most ceramic ring 198 as described hereinabove. The air knife fluid may include any gas sufficient to reduce deposition on the interior walls of the thermal reaction unit while not detrimentally affecting the decomposition treatment in said unit. Gases contemplated include air, CDA, oxygen-enriched air, oxygen, ozone and inert gases, e.g., Ar, N₂, etc. In operation, gas is intermittently injected through the air knife inlet 206 and exits a very thin slit 204 that is positioned parallel to the interior wall of the thermal reaction chamber 32. Thus, gases are directed upwards along the wall (in the direction of the arrows in Fig. 12) to force any deposited particulate matter from the surface of the interior wall.

Example

To demonstrate the abatement effectiveness of the improved thermal reactor described herein, a series of experiments were performed to quantify the efficiency of abatement using said thermal reactor. It can be seen that greater than 99% of the test gases were abated using the improved thermal reactor, as shown in Table 1.

Test gas	Flow rate/slm	Fuel/slm	DRE, %
C ₂ F ₆	2.00	50	> 99.9 %
C ₃ F ₈	2.00	45	> 99.9 %
NF ₃	2.00	33	> 99.9 %
SF ₆	5.00	40	99.6 %
CF ₄	0.25	86	99.5 %
CF ₄	0.25	83	99.5 %

Table 1: Results of abatement experiments using the embodiments described herein.

Although the invention has been variously described herein with reference to illustrative embodiments and features, it will be appreciated that the embodiments and features described hereinabove are not intended to limit the invention, and that other variations, modifications and other embodiments will readily suggest themselves to those of ordinary skill in the art, based on the disclosure herein. The invention therefore is to be broadly construed, consistent with the claims hereafter set forth.

THE INVENTION CLAIMED IS:

1. A thermal reactor for removing pollutant from waste gas, the thermal reactor comprising:

5 a thermal reaction unit comprising:

i) an exterior wall having a plurality of perforations for passage of a fluid therethrough;

10 ii) a porous ceramic interior wall defining a thermal reaction chamber, wherein the interior wall comprises at least two ring sections in a stacked arrangement;

iii) at least one waste gas inlet in fluid communication with the thermal reaction chamber for introducing a waste gas therein; and

15 iv) at least one fuel inlet in fluid communication with the thermal reaction chamber for introducing a fuel for use during decomposition of said waste gas in the thermal reaction chamber; and

v) means for directing a fluid through the one or more perforations of the exterior wall and the porous ceramic interior wall to reduce the deposition and accumulation of particulate matter thereon; and

20 a water quench unit coupled to the thermal reaction unit and adapted to receive a gas stream from the thermal reaction unit.

2. The thermal reactor of claim 1, wherein the thermal reactor is adapted to remove at least one pollutant species selected from the group consisting of CF_4 , C_2F_6 , SF_6 , C_3F_8 , SiF_4 , BF_3 , NF_3 , BH_3 , B_2H_6 , B_5H_9 , NH_3 , PH_3 , SiH_4 , SeH_2 , F_2 , Cl_2 , HCl , HF , HBr , WF_6 , H_2 , $\text{Al}(\text{CH}_3)_3$, primary and secondary amines, organosilanes, organometallics, and halosilanes.

3. The thermal reactor of claim 1, coupled in waste gas receiving relationship to a process facility selected from the group consisting of a semiconductor manufacturing process facility and a liquid crystal display (LCD) process facility.

4. The thermal reactor of claim 1, wherein the porous ceramic interior wall has a generally tubular form.

5. The thermal reactor of claim 4, wherein the generally tubular form comprises a shape selected from the group consisting of cylindrical, polygonal and elliptical shapes.

5

6. The thermal reactor of claim 4, wherein the generally tubular form comprises a cylindrical shape.

7. The thermal reactor of claim 4, wherein each of the at least two ring sections are arcuate in shape.

10

8. The thermal reactor of claim 1, wherein the exterior wall comprises corrosion-resistant and thermally stable metal.

9. The thermal reactor of claim 8, wherein the metal exterior wall comprises a material selected from the group consisting of stainless steel, austenitic nickel-chromium-iron alloys and other nickel-based alloys.

15

10. The thermal reactor of claim 1, wherein the metal exterior wall has perforations that provide a pressure drop across the thermal reaction unit of greater than about 0.1 psi.

20

11. The thermal reactor of claim 1, wherein the total number of perforations in proximity to the waste gas inlet and the fuel inlet is greater than the total number of perforations in proximity to the water quench unit.

25

12. The thermal reactor of claim 1, wherein the thermal reaction unit is adapted so that more fluid flows through the porous ceramic interior wall in proximity to the waste gas inlet and the fuel inlet than in proximity to the water quench unit.

30

13. The thermal reactor of claim 1, wherein the exterior wall includes at least two coupled sections.

14. The thermal reactor of claim 1, further comprising a fibrous material disposed between the exterior wall and the porous ceramic interior wall.

15. The thermal reactor of claim 14, wherein the fibrous material comprises material selected from the group consisting of spinel fibers, glass wool and aluminum silicate.

16. The thermal reactor of claim 1, wherein the porous ceramic interior wall comprises material selected from the group consisting of alumina materials, magnesium oxide, refractory metal oxides, silicon carbide, silicon nitride, and yttria-doped alumina materials.

17. The thermal reactor of claim 16, wherein the yttria-doped alumina material comprises yttria-stabilized zirconia alumina.

18. The thermal reactor of claim 1, wherein the interior wall comprises at least about twenty ring sections.

19. The thermal reactor of claim 1, wherein the at least two ring sections are complementarily jointed for connection of adjacent stacked rings.

20. The thermal reactor of claim 19, wherein the ring sections are complementarily jointed with at least one joint selected from the group consisting of ship-lap joints, beveled joints, butt joints, lap joints and tongue-and-groove joints.

21. The thermal reactor of claim 1, further comprising a fuel supply for delivering fuel to the at least one fuel inlet, wherein the fuel supply comprises fluid selected from the group consisting of methane, hydrogen, natural gas, propane, LPG and city gas.

22. The thermal reactor of claim 1, further comprising at least one oxidant inlet in fluid communication with the thermal reaction chamber for introducing oxidant to blend with the fuel.

23. The thermal reactor of claim 22, further comprising an oxidant supply for delivering oxidant to the at least one oxidant inlet, wherein said oxidant supply comprises an oxidant selected from the group consisting of air, oxygen, ozone, oxygen-enriched air and clean dry air (CDA).

24. The thermal reactor of claim 1, wherein the means for directing fluid through the one or more perforations of the exterior wall and the porous ceramic interior wall is adapted to supply a fluid that comprises a species selected from the group consisting of an inert gas, air, CDA, oxygen-enriched air, oxygen, ozone, argon and nitrogen.

25. The thermal reactor of claim 1, wherein the water quench unit comprises at least one of a water curtain and water spray.

26. The thermal reactor of claim 1, wherein the thermal reaction unit further comprises a porous ceramic plate positioned at or within the interior wall of the thermal reaction chamber, and wherein the porous ceramic plate encloses one end of said thermal reaction chamber.

27. The thermal reactor of claim 26, further comprising means for directing fluid through the porous ceramic plate to reduce deposition and accumulation of particulate matter thereon.

28. The thermal reactor of claim 26, further comprising a center jet in fluid communication with the thermal reaction chamber, wherein the center jet is in proximity to the at least one waste gas inlet and the at least one fuel inlet, and wherein the center jet is adapted to introduce high velocity fluid into the thermal reaction chamber through the center jet during decomposition of the waste gas to inhibit deposition and accumulation of particulate matter on the interior wall and porous ceramic plate of the thermal reaction chamber proximate to the center jet.

29. The thermal reactor of claim 28, wherein center jet is adapted to introduce high velocity fluid selected from the group consisting of an inert gas, air, CDA, oxygen-enriched air, oxygen, ozone, argon and nitrogen.

5 30. The thermal reactor of claim 1, further comprising a water resistant shield between the thermal reaction unit and the water quench unit.

31. The thermal reactor of claim 1, wherein the thermal reaction unit is adapted to operate at an internal temperature from about 500°C to about 2000°C.

10 32. The thermal reactor of claim 1, further comprising an outer reactor shell having an outer reactor shell interior wall, wherein an annular space is formed between the outer reactor shell interior wall and the exterior wall of the thermal reaction unit.

15 33. The thermal reactor of claim 32, further comprising at least one port formed within the outer reactor shell and adapted to allow fluid to be flowed into the annular space and through the porous ceramic interior wall and into the thermal reaction chamber.

20 34. The thermal reactor of claim 1, wherein the at least one waste gas inlet has an interior wall, and wherein the interior wall is coated with at least one layer of a coating material comprising a fluoropolymer.

25 35. The thermal reactor of claim 1, wherein the porous ceramic interior wall comprises a reticulated ceramic interior wall.

36. The thermal reactor of claim 35 wherein the reticulated ceramic interior wall comprises material selected from the group consisting of alumina materials, magnesium oxide, refractory metal oxides, silicon carbide, silicon nitride, and yttria-doped alumina materials.

30 37. A thermal reactor for removing pollutant from waste gas, the thermal reactor comprising:

a thermal reaction unit comprising:

i) an exterior wall having a generally tubular form;
ii) an interior wall having a generally tubular form and concentric with the exterior wall, wherein the interior wall defines a thermal reaction chamber;
iii) a porous ceramic plate positioned at or within the interior wall of the thermal reaction unit, wherein the porous ceramic plate encloses one end of the thermal reaction chamber;
iii) at least one waste gas inlet in fluid communication with the thermal reaction chamber for introducing a waste gas therein; and
iv) at least one fuel inlet in fluid communication with the thermal reaction chamber for introducing a fuel for use during decomposition of said waste gas within the thermal reaction unit; and
a water quench unit coupled to the thermal reactor unit.

38. The thermal reactor of claim 37, wherein the porous ceramic plate comprises a reticulated ceramic plate.

39. The thermal reactor of claim 38, wherein the reticulated ceramic plate comprises material selected from the group consisting of alumina materials, magnesium oxide, refractory metal oxides, silicon carbide, silicon nitride, and yttria-doped alumina materials.

40. The thermal reactor of claim 39, wherein the yttria-doped alumina material comprises yttria-stabilized zirconia alumina.

41. The thermal reactor of claim 37, further comprising means for directing fluid through the porous ceramic plate to reduce the deposition and accumulation of particulate matter thereon.

42. An apparatus for use during the abatement of a semiconductor manufacturing process comprising:

a thermal reaction unit having:
an interior porous wall that defines a central chamber, the interior porous wall formed from a plurality of stacked porous sections;

at least one waste gas inlet in fluid communication with the central chamber and adapted to introduce a gaseous waste stream to the central chamber;

a thermal mechanism positioned within the central chamber and adapted to decompose the gaseous waste stream within the central chamber, thereby

5 forming reaction products; and

a fluid delivery system adapted to provide a fluid to the central chamber through the interior porous wall at a sufficient force to reduce deposition of reaction products on an inner surface of the interior porous wall of the central chamber.

10 43. The apparatus of claim 42, wherein the interior porous wall has a generally tubular form.

44. The apparatus of claim 42, wherein each of the stacked porous sections are arcuate in shape.

15

45. The apparatus of claim 42, wherein the interior porous wall comprises at least about twenty stacked porous sections.

20

46. The apparatus of claim 42, wherein the stacked porous sections are complementarily jointed for connection of adjacent porous sections.

47. The apparatus of claim 46, wherein each stacked porous section is complementarily jointed with at least one joint selected from the group consisting of ship-lap joints, beveled joints, butt joints, lap joints and tongue-and-groove joints.

25

48. The apparatus of claim 42, wherein each stacked porous section comprises a porous ceramic.

30

49. The apparatus of claim 42, wherein each stacked porous section comprises a reticulated ceramic.

50. The apparatus of claim 49 wherein each stacked porous section comprises material selected from the group consisting of alumina materials, magnesium oxide, refractory metal oxides, silicon carbide, silicon nitride, and yttria-doped alumina materials.

5 51. The apparatus of claim 42, wherein the thermal reaction chamber is adapted so that more fluid flows through the interior porous wall in proximity to the waste gas inlet than in proximity to an outlet of the thermal reaction unit.

10 52. The apparatus of claim 42 further comprising a first exterior wall that surrounds the interior porous wall, the first exterior wall having a plurality of perforations for passage of fluid through the first exterior wall to the interior porous wall.

53. The apparatus of claim 52, wherein the first exterior wall comprises corrosion-resistant and thermally stable metal.

15 54. The apparatus of claim 53, wherein the first exterior wall comprises a material selected from the group consisting of stainless steel, austenitic nickel-chromium-iron alloys and other nickel-based alloys.

20 55. The apparatus of claim 52 further comprising:
a second exterior wall that surrounds the first exterior wall and the interior porous wall and that defines an interior space between the second exterior wall and the first exterior wall;
wherein the fluid delivery system is adapted to provide a fluid to the central
25 chamber through the interior porous wall by providing fluid to the interior space between the second exterior wall and the first exterior wall.

56. The apparatus of claim 42 further comprising:
a second reaction chamber coupled to the thermal reaction unit and having:
30 a gas flow chamber in fluid communication with the central chamber, the gas flow chamber having an inlet and outlet for passing the gaseous waste stream and reaction products through the gas flow chamber; and

a water delivery system adapted to generate a flowing liquid film on an interior surface of the gas flow chamber so as to reduce deposition and accumulation of particulate solids on the interior surface of the gas flow chamber.

- 5 57. An apparatus for use during the abatement of a semiconductor manufacturing process comprising:
- a upper reaction chamber having:
- an interior porous wall that defines a central chamber, the interior porous wall formed from a plurality of stacked, replaceable porous sections;
- 10 a first exterior wall that surrounds and supports the stacked porous sections of the interior porous wall and that includes a plurality of perforations that allow passage of fluid through the first exterior wall to the interior porous wall;
- a second exterior wall that surrounds the first exterior wall and the interior porous wall and that defines an interior space between the second exterior wall
- 15 and the first exterior wall;
- at least one waste gas inlet in fluid communication with the central chamber and adapted to introduce a gaseous waste stream to the central chamber;
- at least one fuel inlet in fluid communication with the central chamber and adapted to introduce fuel to the central chamber;
- 20 a thermal mechanism positioned within the central chamber and adapted to decompose the gaseous waste stream within the central chamber, thereby forming reaction products; and
- a fluid delivery system adapted to provide a fluid to the central chamber through the interior porous wall at a sufficient force to reduce deposition of
- 25 reaction products on an inner surface of the interior porous wall of the central chamber;
- and
- a lower reaction chamber coupled to the upper reaction chamber and having:
- a gas flow chamber in fluid communication with the central
- 30 chamber, the gas flow chamber having an inlet and outlet for passing the gaseous waste stream and reaction products through the gas flow chamber; and

a water delivery system adapted to generate a flowing liquid film on an interior surface of the gas flow chamber so as to reduce deposition and accumulation of particulate solids on the interior surface of the gas flow chamber.

5 58. The system of claim 57 further comprising an interior porous plate that encloses an inlet end of the central chamber, the interior porous plate adapted to pass a fluid through the interior porous plate to the central chamber so as to reduce deposition of particulate matter on an interior surface of the interior porous plate.

10 59. The system of claim 57 further comprising at least one inlet adapted to introduce fluid to a gas stream as the gas stream travels from the upper reaction chamber to the lower reaction chamber.

 60. The system of claim 57 further comprising a drainage tank coupled to the
15 lower reaction chamber having headspace adapted to receive a gaseous waste stream from the lower reaction chamber.

 61. The system of claim 60 further comprising at least one scrubbing unit adapted to receive the gaseous waste stream from the headspace of the drainage tank.

20

 62. A replacement part for use in an abatement system comprising:
 a stackable and replaceable porous chamber section having a plurality of features that allow the porous chamber section to be stacked with other porous chamber sections so as to form a porous wall that defines a central chamber for use during
25 decomposition of gaseous waste from a semiconductor manufacturing process, the porous chamber section having sufficient porosity to allow transfer of fluid from outside the porous chamber section through the porous chamber section and into the central chamber during a decomposition process performed within the central chamber so as to reduce movement of reaction products toward an interior surface of the porous chamber section.

30

 63. The replacement part of claim 62, wherein the porous chamber section comprises a reticulated ceramic.

64. The replacement part of claim 63 wherein the porous chamber section comprises material selected from the group consisting of alumina materials, magnesium oxide, refractory metal oxides, silicon carbide, silicon nitride, and yttria-doped alumina materials.

5

65. The replacement part of claim 62, wherein the porous chamber section is complementarily jointed for connection with other porous chamber sections.

66. The replacement part of claim 65, wherein the porous chamber section is
10 complementarily jointed with at least one joint selected from the group consisting of ship-lap joints, beveled joints, butt joints, lap joints and tongue-and-groove joints.

67. A replacement part for use in an abatement system comprising:
a shield configured to:

15

be positioned between a quench unit and a porous wall that defines
a central chamber for use during decomposition of gaseous waste from a semiconductor
manufacturing process; and

prevent the porous wall of the central chamber from getting wet during
operation of the quench unit.

20

68. The replacement part of claim 67 wherein shield is L-shaped.

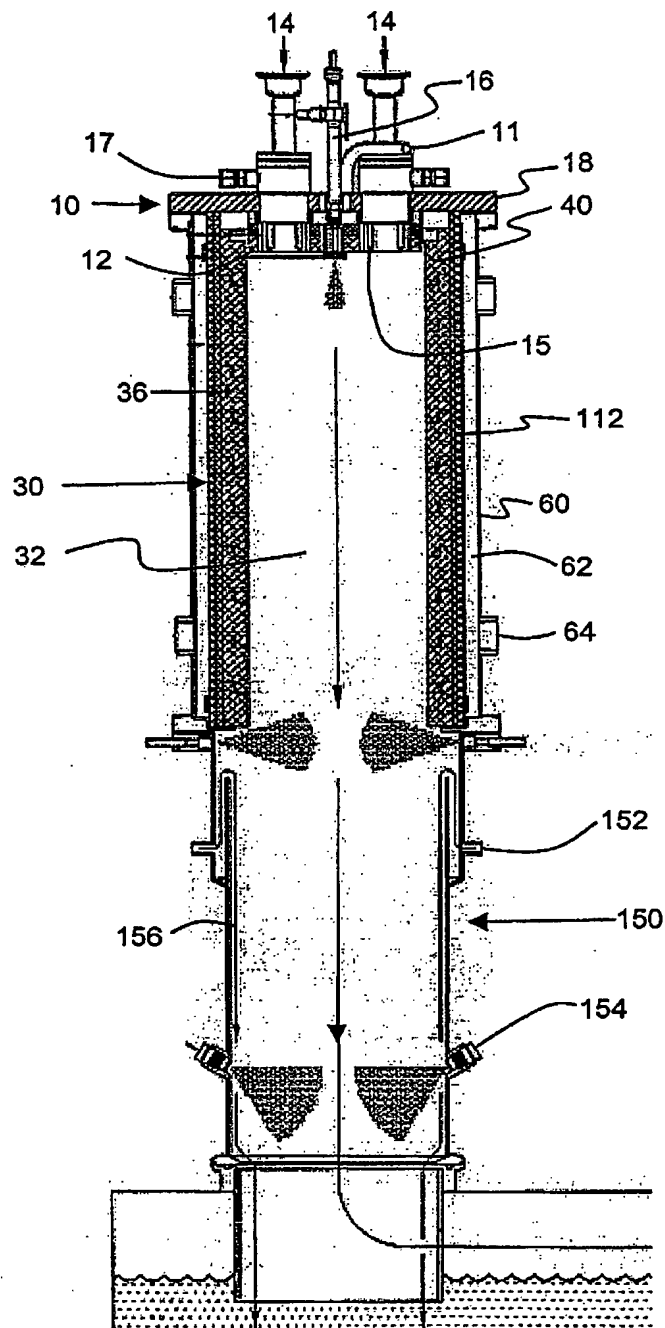
69. The replacement part of claim 67 wherein the shield is configured to
assume a three-dimensional form of a bottom portion of the porous wall.

25

70. The replacement part of claim 69 wherein the porous wall includes a
bottom-most ceramic ring and wherein the shield is a ring that prevents water from
coming into contact with the bottom-most ceramic ring.

30

71. The replacement part of claim 67 wherein the shield comprises a material
selected from the group consisting of stainless steel, austenitic nickel-chromium-iron
alloys and other nickel-based alloys.



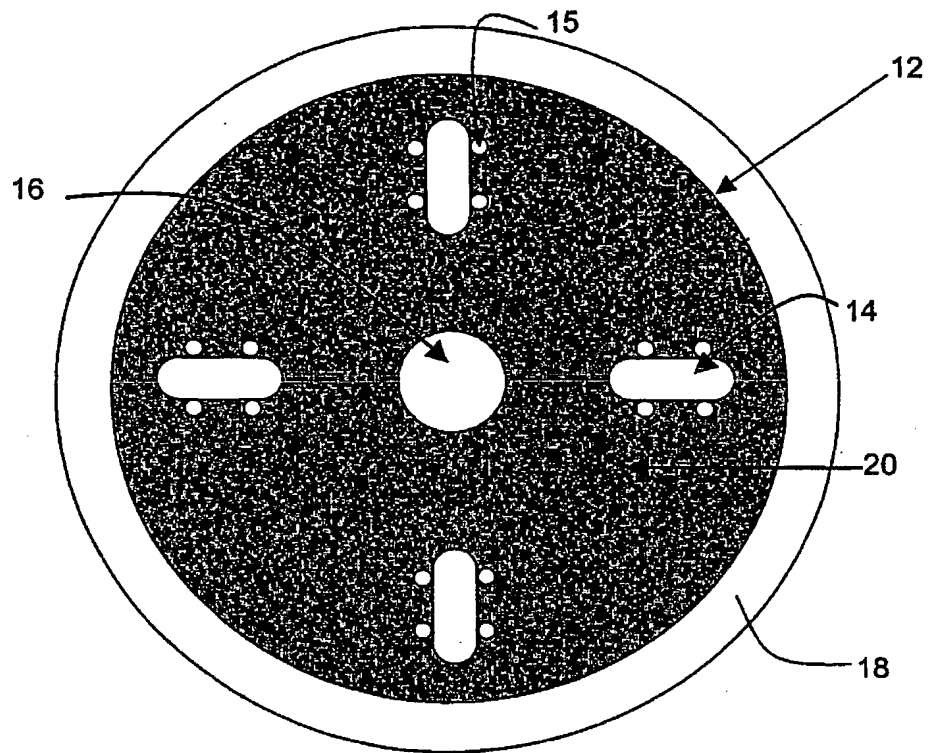


FIGURE 2

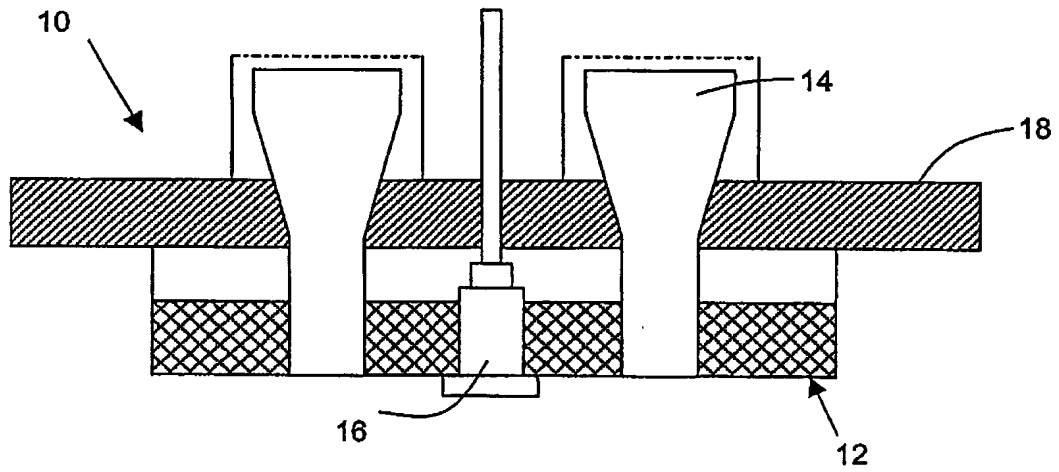


FIGURE 3

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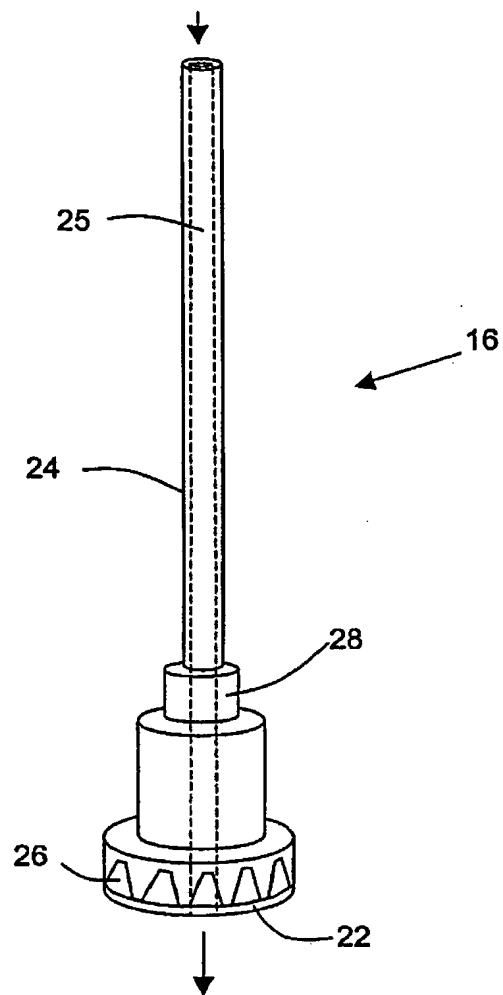
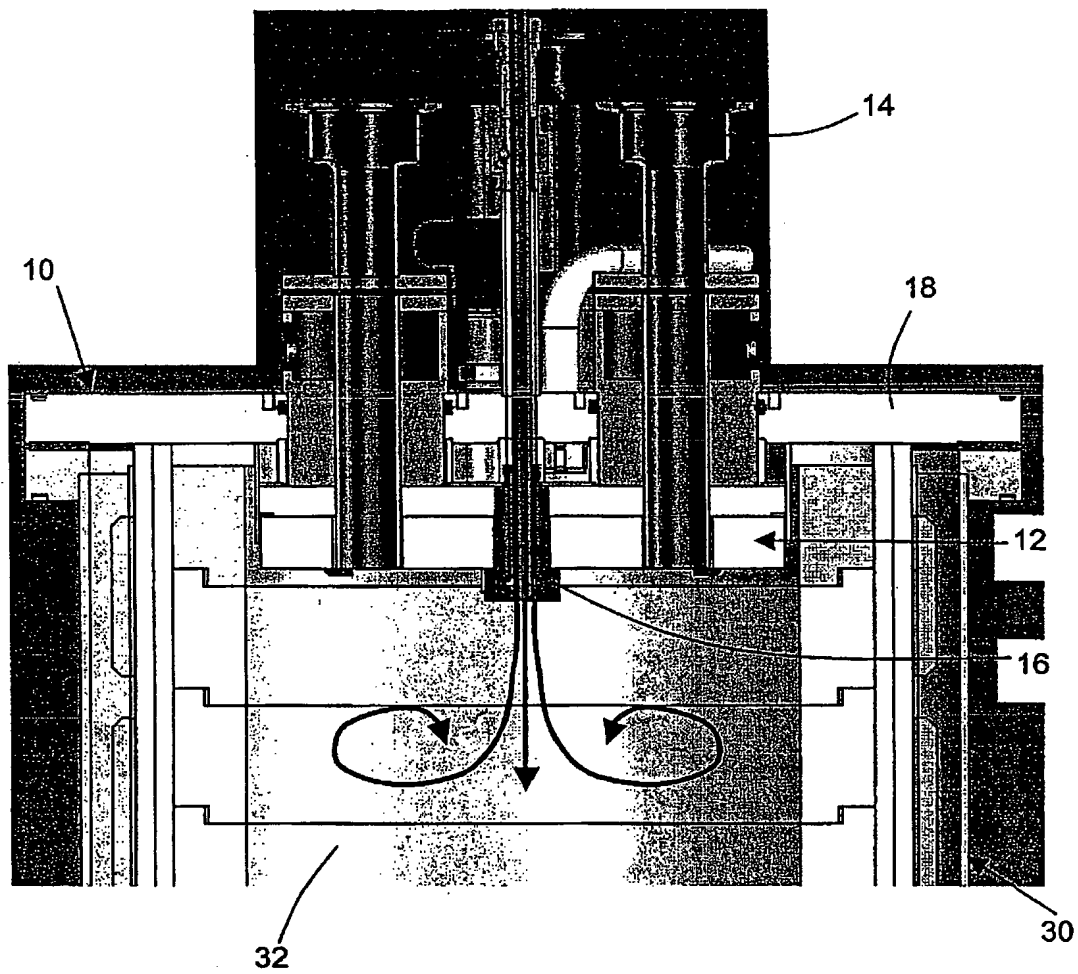


FIGURE 4

**FIGURE 5**

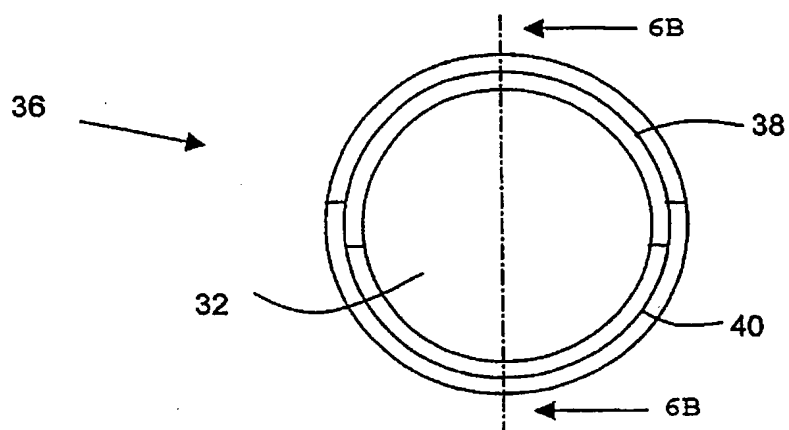


FIGURE 6A

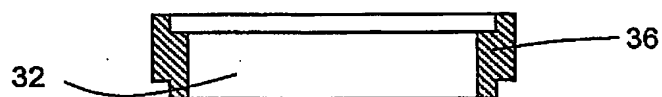


FIGURE 6B

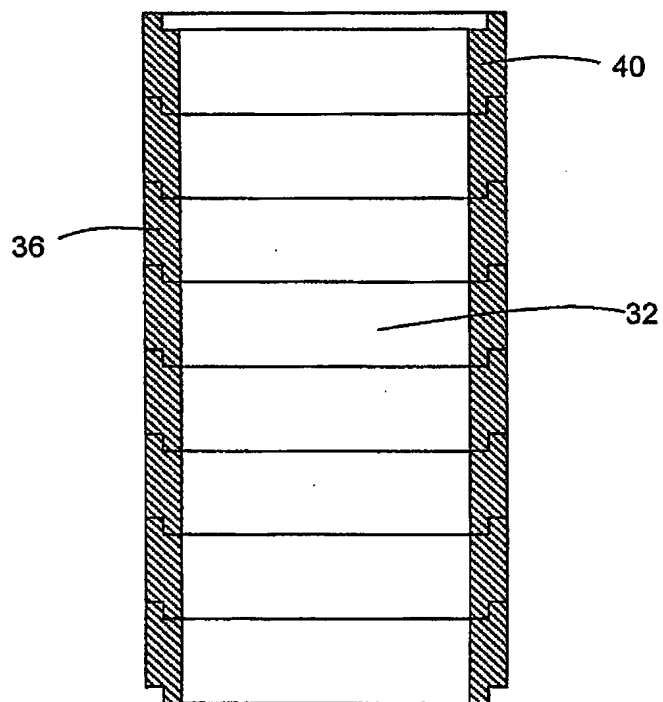


FIGURE 6C

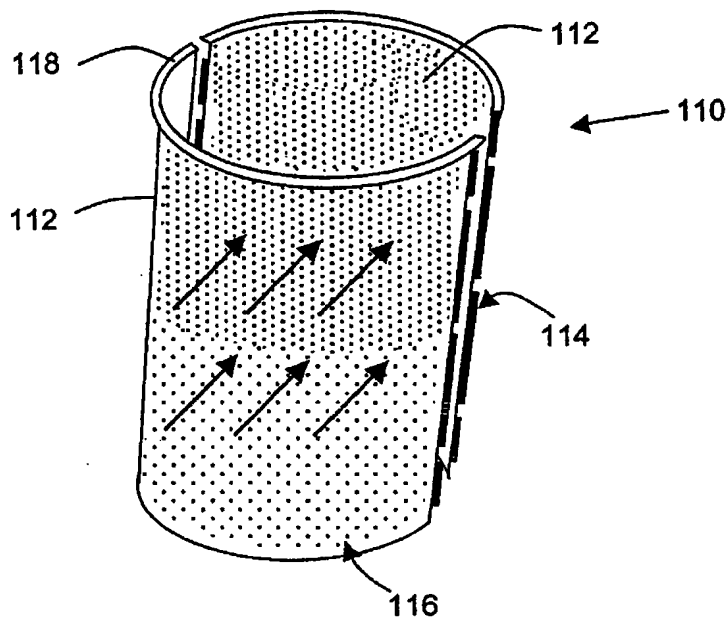


FIGURE 7

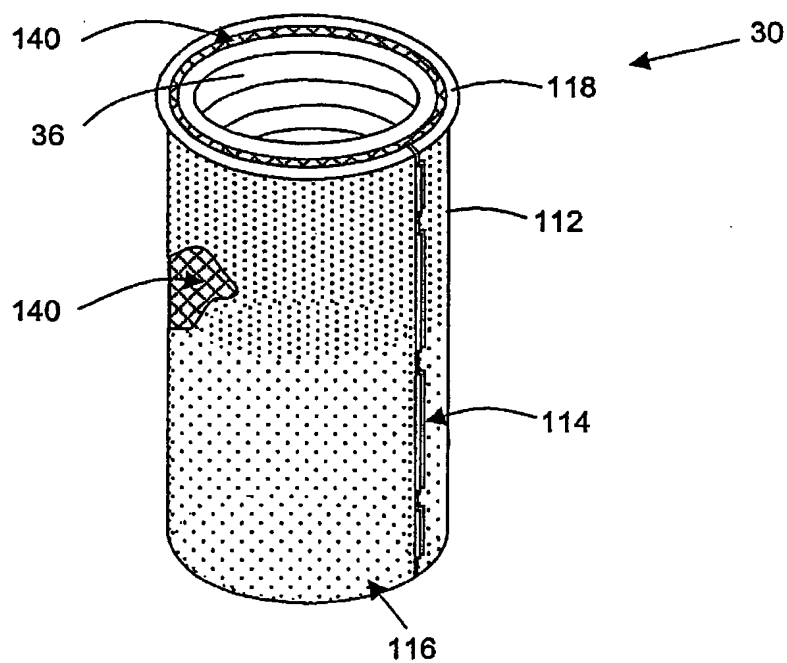


FIGURE 8

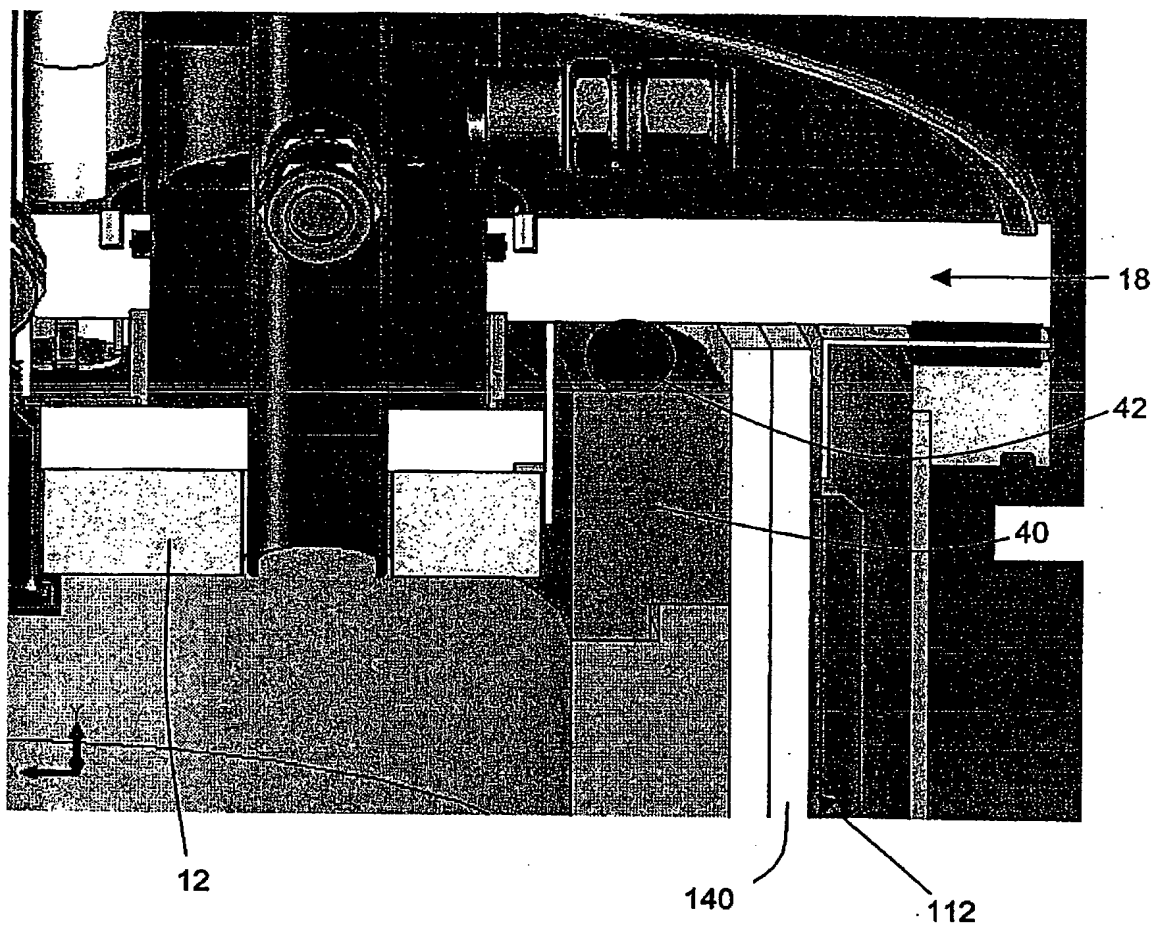


FIGURE 9

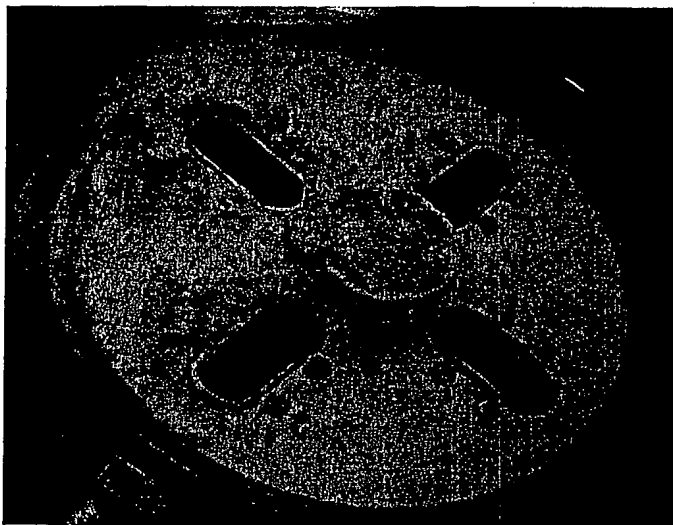
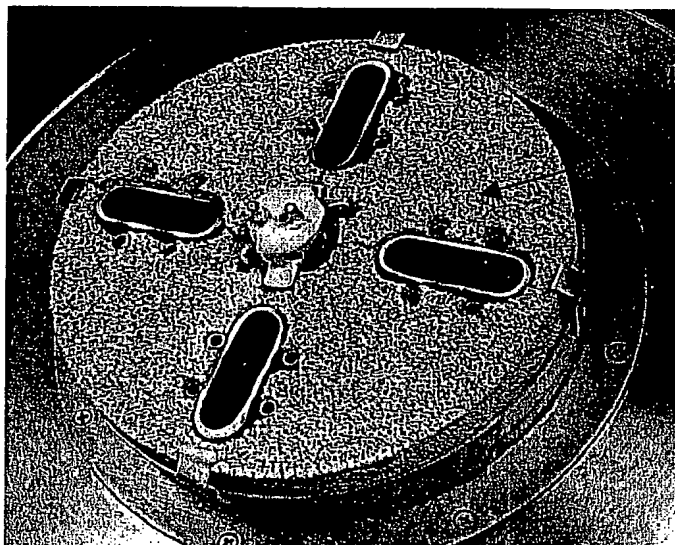


FIGURE 10A
(Prior Art)



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FIGURE 10B

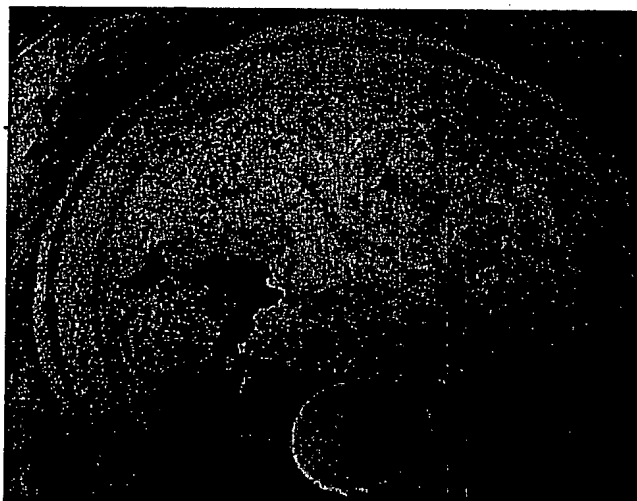


FIGURE 11A
(Prior Art)

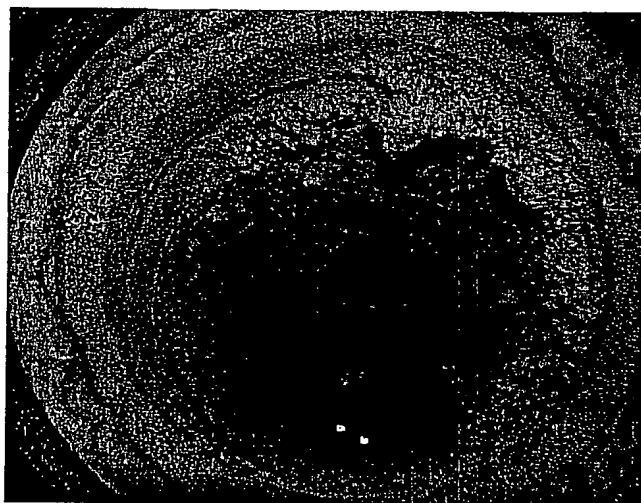


FIGURE 11B

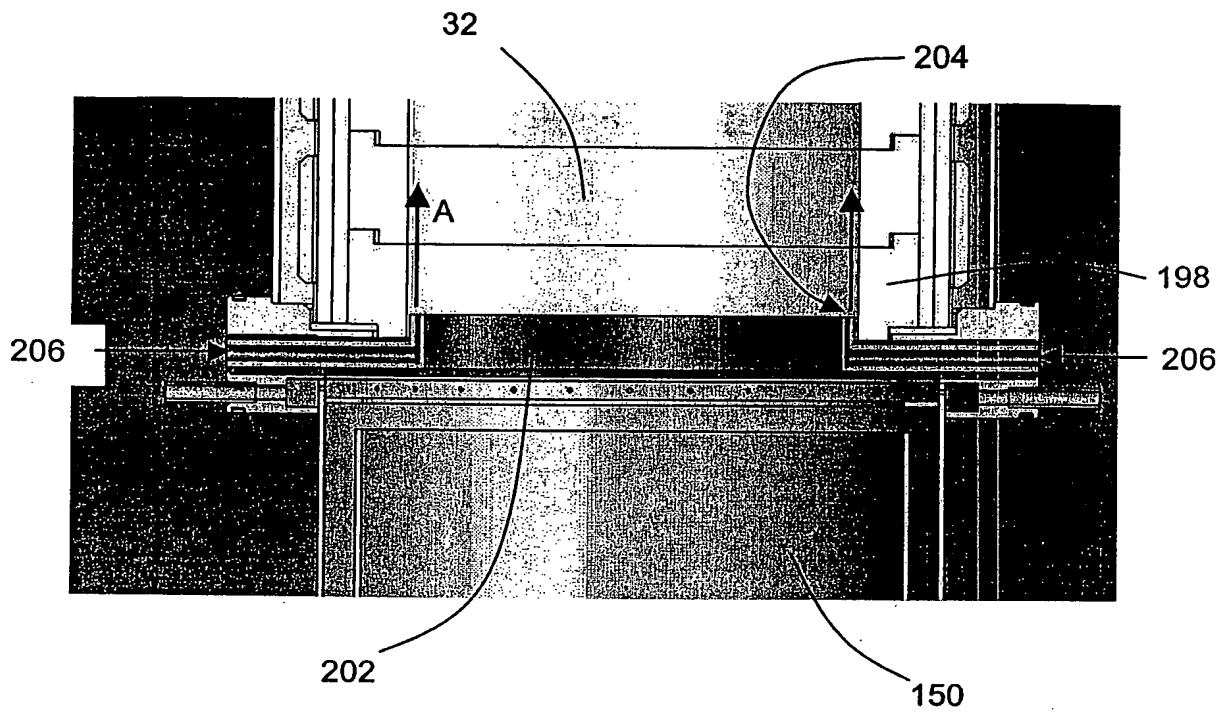


FIGURE 12